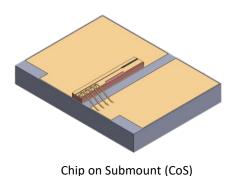
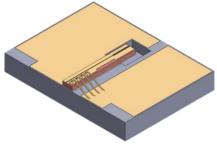
# Photodigm VVV

# Specification Sheet | 737 nm Series

Distributed Bragg Reflector (DBR) Laser Diode





CoS + Mode-Hop Free (MHF)

#### Description

The 737 nm DBR Series of high-performance edge-emitting laser diodes are based on Photodigm's advanced monolithic single-frequency Gallium Arsenide (GaAs) based laser technology. It provides a single spatial mode beam and has passivated facets for reliability. The 737 nm Series DBR devices are used in NV-center research and optical-pumped magnetometry applications.

## 737 nm DBR Chip on Submount (CoS) Characteristics

|   | Chip Architecture |  |
|---|-------------------|--|
| Parameters <sup>1</sup>                     | High Power        |  |
| Wavelength, Nominal (nm) <sup>2</sup>       | 737 ± 0.6         |  |
| Power Range (mW)                            | 40–80             |  |
| Operating Current, Max (CW & Pulsed) (mA)   | 200               |  |
| Optical Power at Max Operating Current (mW) | 80                |  |
| Slope Efficiency, Nominal (W/A)             | 0.8               |  |
| Threshold Current, Nominal (mA)             | 80                |  |

1. Characteristics at T<sub>c</sub> = 25 °C unless otherwise specified. Operating outside of these parameters voids warranty.

2. Hermetically sealed packages may contain CoS that are  $\pm$  1.2 nm from nominal.

## Available Free-Space Package Add-ons





C-Mount



Transmitter Optical Subassembly (TOSA)



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## **Specifications**

#### Laser

| Parameter   | Unit             | Min | Typical | Max    |
|---|------------------|-----|---------|--------|
| Storage Temperature                                       | °C               | 0   | -       | 70     |
| Operating Temperature at case                             | °C               | 5   | -       | 70     |
| Operating Temperature at laser chip <sup>1</sup>          | °C               | 5   | -       | 45     |
| Laser Series Resistance                                   | Ω                | -   | 2       | -      |
| Laser Forward Voltage @ LIV Current                       | V                | -   | 2       | -      |
| Nominal Laser Linewidth @ LIV Current                     | kHz              | -   | 500     | -      |
| Beam Divergence @ FWHM ( $\theta_{  } x \theta_{\perp}$ ) | Q                | -   | 6 x 28  | 8 x 32 |
| Side Mode Suppression Ratio (SMSR)                        | dB               | -   | -40     | -      |
| Polarization Extinction Ratio                             | dB               | -17 | -20     | -      |
| Laser Polarization  | TE               |     |         |        |
| Mode Structure  | Fundamental Mode |     |         |        |
| Temperature Tuning Rate                                   | nm/°C            | -   | 0.06    | -      |
| Current Tuning Rate                                       | nm/mA            | -   | 0.002   | -      |
| Laser Reverse Voltage                                     | V                | -   | -       | 0      |

1. Operation below dew point not recommended without hermetically sealed packaged

#### Free-Space Package Add-Ons

| Parameter                  | Unit | Min  | Typical | Max |
|----------------------------|------|------|---------|-----|
| Photodiode Forward Current | mA   | -    | -       | 10  |
| Photodiode Reverse Voltage | V    | -    | -       | 50  |
| TEC Current (TOSA)         | А    | -1.1 | -       | 1.1 |
| TEC Voltage (TOSA)         | V    | -3.0 | -       | 3.0 |
| TEC Current (TO-8)         | А    | -1.8 | -       | 1.8 |
| TEC Voltage (TO-8)         | V    | -2.2 | -       | 2.2 |
| Thermistor Resistance      | kΩ   | -    | 10      | -   |

## **Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.



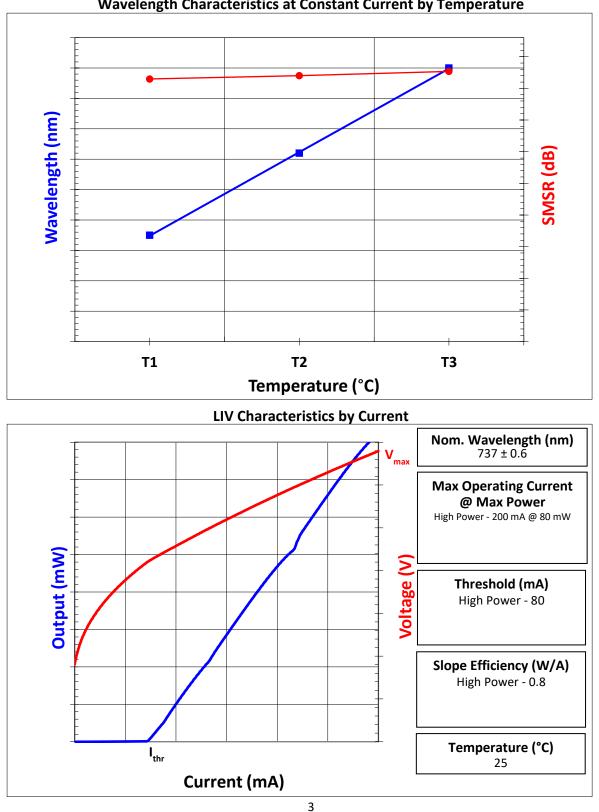


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#### Wavelength Characteristics at Constant Current by Temperature

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